

# isc N-Channel MOSFET Transistor

# **TK17N65W**

### FEATURES

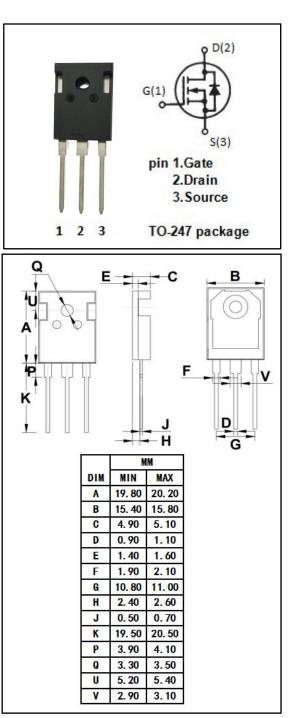
- Low drain-source on-resistance: R⊳s(on) ≤0.2Ω.
- Enhancement mode:
  - Vth =2.5 to 3.5V (Vps = 10 V, Ip=0.9mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRITION

Switching Voltage Regulators

#### ABSOLUTE MAXIMUM RATINGS(Ta=25°C) VALUE UNIT SYMBOL PARAMETER Drain-Source Voltage 650 V VDSS V<sub>GS</sub> Gate-Source Voltage $\pm 30$ v **Drain Current-Continuous** 17.3 А Ь Drain Current-Single Pulsed **I**DM 69.2 А $\mathbf{P}_{\mathsf{D}}$ Total Dissipation @Tc=25°C 165 W Max. Operating Junction Temperature 150 °C Tj -55~150 °C Storage Temperature Tstg THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.757	°C/W



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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\rm C}\text{=}25^\circ\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =10mA	650			V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.9mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =8.7A			0.2	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			10	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =17.3A, V <sub>GS</sub> = 0 V			1.7	V



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